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Intersil HI3-0518-5

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Datasheet of HI3-0518-5 - IC MULTIPLEXER 8X1 18DIP

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HI-518

Data Sheet January 23, 2006 FN3147.4

8-Channel/Differential 4-Channel, CMOS High Speed Analog Multiplexer

The HI-518 is a monolithic, dielectrically isolated, high speed, high performance CMOS analog multiplexer. It offers unique built-in channel selection decoding plus an inhibit input for disabling all channels. The dual function of address input A2 enables the HI-518 to be user programmed either as a single ended 8-Channel multiplexer by connecting 'Out A' to 'Out B' and using A2 as a digital address input, or as a 4-Channel differential multiplexer by connecting A2 to the Vsupply. The substrate leakages and parasitic capacitances are reduced substantially by using the Intersil Dielectric Isolation process to achieve optimum performance in both high and low level signal applications. The low output leakage current (I_{D(OFF)} < 100pA at 25^oC) and fast settling (tSFTTLF = 800ns to 0.01%) characteristics of the device make it an ideal choice for high speed data acquisition systems, precision instrumentation, and industrial process control.

Ordering Information

PART NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE	PKG. DWG.#
HI3-0518-5	HI3-518-5	0 to 75	18 Ld PDIP	E18.3
HI3-0518-5Z (See Note)	HI3-518-5Z	0 to 75	18 Ld PDIP* (Pb-free)	E18.3
HI1-0518-8		-55 to 125	18 Ld CERDIP	F18.3

^{*}Pb-free PDIPs can be used for through hole wave solder processing only. They are not intended for use in Reflow solder processing applications.

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Features

•	Access Time (Typical)
•	Settling Time
•	Low Leakage (Typical) 10pA - I _{D(OFF)} 15pA
•	Low Capacitance (Max) 5pF - C _{S(OFF)} 10pF
•	Off Isolation at 500kHz
•	Low Charge Injection Error
•	Single Ended to Differential Selectable (SDS)
_	Lacia Laval Calactable (LLC)

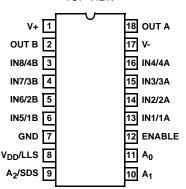
- Logic Level Selectable (LLS)
- · Pb-Free Plus Anneal Available (RoHS Compliant)

Applications

- · Data Acquisition Systems
- · Precision Instrumentation
- Industrial Control

Pinout

HI-518 (CERDIP, PDIP) TOP VIEW



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Truth Tables

TABLE 1. HI-518 USED AS AN 8-CHANNEL MULTIPLEXER OR DUAL 4-CHANNEL MULTIPLEXER (NOTE 1)

USE A ₂ AS D	DIGITAL A	ON CHAI	NNEL TO		
ENABLE	A ₂	A ₁	A ₀	OUT A	OUT B
L	Х	Х	Х	None	None
Н	L	L	L	1A	None
Н	L	L	Н	2A	None
Н	L	Н	L	3A	None
Н	L	Н	Н	4A	None
Н	Н	L	L	None	1B
Н	Н	L	Н	None	2B
Н	Н	Н	L	None	3B
Н	Н	Н	Н	None	4B

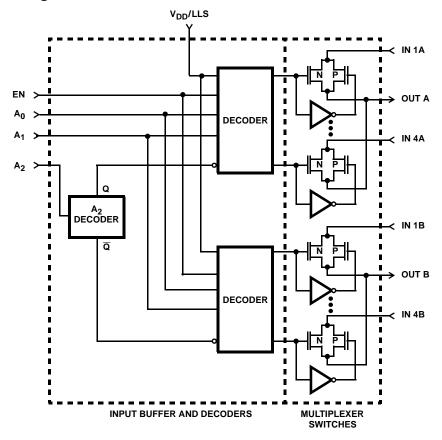
TABLE 2. HI-518 USED AS A DIFFERENTIAL 4-CHANNEL MULTIPLEXER

A ₂ CONNECTED TO V- SUPPLY			ON CHAI	NNEL TO
ENABLE	A ₁ A ₀		OUT A	OUT B
L	Х	Х	None	None
Н	L	L	1A	1B
Н	L	Н	2A	2B
Н	Н	L	3A	3B
Н	Н	Н	4A	4B

NOTE:

 For 8-Channel single ended function, tie "Out A" to "Out B"; for dual 4-Channel function, use the A₂ address pin to select between Mux A and Mux B, where Mux A is selected with A₂ low.

Functional Block Diagram



A ₂ DECODE						
A ₂	Q	Q				
Н	Н	mL				
L	L	Н				
V-	L	L				



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Absolute Maximum Ratings	Thermal Information				
$ \begin{array}{llllllllllllllllllllllllllllllllllll$	Thermal Resistance (Typical, Note 2)θ _{JA} (°C/W) θ _{JC} (°C/W) PDIP Package*				
Operating ConditionsTemperature Ranges-55°C to 125°CHI-518-80°C to 75°C	*Pb-free PDIPs can be used for through hole wave solder processin only. They are not intended for use in Reflow solder processing applications.				

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE

2. $\theta_{\mbox{\scriptsize JA}}$ is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications Supplies = +15V, -15V; V_{AH} (Logic Level High) = 2.4V, V_{AL} (Logic Level Low) = 0.8V; V_{DD}/LLS = GND (Note 3), Unless Otherwise Specified

	TEST	TEMP		-8		-5			
PARAMETER	CONDITIONS	(°C)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS	<u>.</u>								
Access Time, t _A		25	-	130	175	-	130	175	ns
		Full	-	-	225	-	1	225	ns
Break-Before-Make Delay, t _{OPEN}		25	10	20	-	10	20	-	ns
Enable Delay (ON), t _{ON(EN)}		25	-	120	175		120	175	ns
Enable Delay (OFF), t _{OFF(EN)}		25	-	140	175		140	175	ns
Settling Time	To 0.1%	25	-	250	-	-	250	-	ns
	To 0.01%	25	-	800	-	-	800	-	ns
Charge Injection Error	Note 6	25	-	-	25	-	-	25	mV
Off Isolation	Note 7	25	45	-	-	45	-	-	dB
Channel Input Capacitance, C _{S(OFF)}		25	-	-	5	-	-	5	pF
Channel Output Capacitance, C _{D(OFF)}		25	-	-	10	-	-	10	pF
Digital Input Capacitance, CA		25	-	-	5	-	-	5	pF
Input to Output Capacitance, C _{DS(OFF)}		25	-	0.02	-	-	0.02	-	pF
DIGITAL INPUT CHARACTERISTICS	<u> </u>		1						
Input Low Threshold, V _{AL} (TTL)	Note 3	Full	-	-	0.8	-	-	0.8	V
Input High Threshold, V _{AH} (TTL)	Note 3	Full	2.4	-	-	2.4	1	-	V
Input Low Threshold, V _{AL} (CMOS)	Note 3	Full	-	-	0.3V _{DD}	-	1	0.3V _{DD}	V
Input High Threshold, V _{AH} (CMOS)	Note 3	Full	0.7V _{DD}	-	-	0.7V _{DD}	-	-	V
Input Leakage Current, I _{AH} (High)		Full	-	-	1	-	-	1	μА
Input Leakage Current, I _{AL} (Low)		Full	-	-	20	-	-	20	μΑ
ANALOG CHANNEL CHARACTERISTIC	S				1			1	ı
Analog Signal Range, V _{IN}	Note 4	Full	-14	-	+14	-15	-	+15	V
On Resistance, r _{ON}	Note 5	25	-	480	750	-	480	750	Ω
		Full	-	-	1,000	-	1	1,000	Ω
Off Input Leakage Current, I _{S(OFF)}		25	-	0.01	-	-	0.01	-	nA
-(- /		Full	-	-	50	-	1	50	nA
Off Output Leakage Current, I _{D(OFF)}		25	-	0.015	-	-	0.015	-	nA
ζ- /		Full	-	-	50	-	-	50	nA
On Channel Leakage Current, I _{D(ON)}		25	-	0.015	-	-	0.015	-	nA
- (,		Full	-	-	50	-	-	50	nA
POWER SUPPLY CHARACTERISTICS	*	•			•			•	
Power Dissipation, P _D		Full	-	-	450	-	-	540	mW

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Electrical Specifications Supplies = +15V, -15V; V_{AH} (Logic Level High) = 2.4V, V_{AL} (Logic Level Low) = 0.8V; $V_{DD}/LLS = GND$ (Note 3), Unless Otherwise Specified **(Continued)**

	TEST	TEMP	-8		-5				
PARAMETER	CONDITIONS	(°C)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
I+, Current	$V_{EN} = 2.4V$	Full	-	-	15	-	-	18	mA
I-, Current		Full	-	-	15	-	-	18	mA

NOTES:

- 3. V_{DD}/LLS pin = open or grounded for TTL compatibility. V_{DD}/LLS pin = V_{DD} for CMOS compatibility.
- 4. At temperatures above 90° C, care must be taken to assure V_{IN} remains at least 1.0V below the V_{SUPPLY} for proper operation.
- 5. $V_{IN} = \pm 10V$, $I_{OUT} = -100\mu A$.
- 6. $V_{IN} = 0V$, $C_L = 100 pF$, enable input pulse = 3V, f = 500 kHz.
- 7. $C_L = 40pF$, $R_L = 1K$, $V_{EN} = 0.8V$, $V_{IN} = 3V_{RMS}$, f = 500kHz. Due to the pin to pin capacitance between IN 8/4B and OUT B, channel 8/4B exhibits 60dB of OFF isolation under the above test conditions.

Test Circuits and Waveforms V_{DD}/LLS = GND, Unless Otherwise Specified

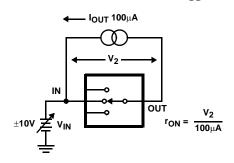


FIGURE 1. ON RESISTANCE TEST CIRCUIT

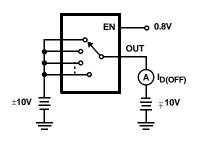


FIGURE 2. ID(OFF) TEST CIRCUIT (NOTE 8)

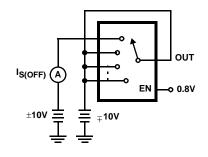


FIGURE 3. I_{S(OFF)} TEST CIRCUIT (NOTE 8)

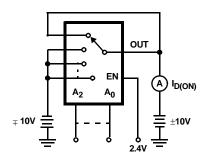


FIGURE 4. I_{D(ON)} TEST CIRCUIT (NOTE 8)

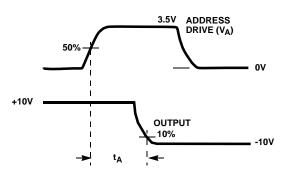


FIGURE 5A. MEASUREMENT POINTS

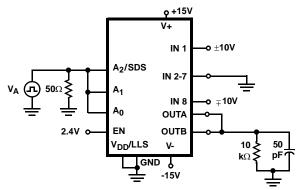


FIGURE 5B. TEST CIRCUIT

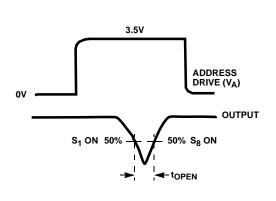
FIGURE 5. ACCESS TIME

NOTE:

8. Two measurements per channel: $\pm 10V$ and $\mp 10V$. (Two measurements per device for $I_{D(OFF)} \pm 10V$ and $\mp 10V$.)

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Test Circuits and Waveforms V_{DD}/LLS = GND, Unless Otherwise Specified (Continued)



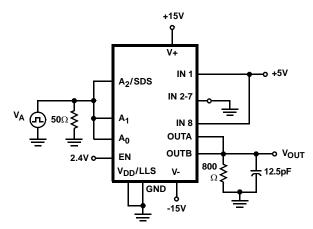
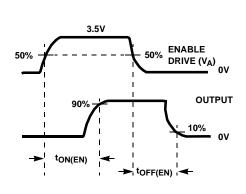


FIGURE 6A. MEASUREMENT POINTS

FIGURE 6B. TEST CIRCUIT

FIGURE 6. BREAK-BEFORE-MAKE DELAY



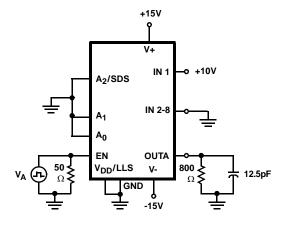
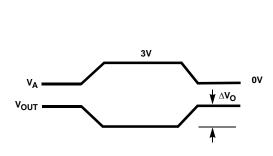


FIGURE 7A. MEASUREMENT POINTS

FIGURE 7B. TEST CIRCUIT

FIGURE 7. ENABLE DELAY



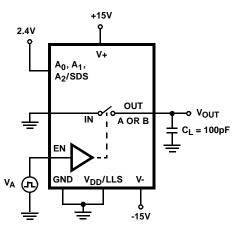


FIGURE 8A. MEASUREMENT POINTS

FIGURE 8B. TEST CIRCUIT

 ΔV_O is the measured voltage error due to charge injection. The error in coulombs is Q = C_L x $\Delta V_O.$

FIGURE 8. CHARGE INJECTION



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Die Characteristics

DIE DIMENSIONS:

89 mils x 93 mils

METALLIZATION:

Type: AlCu

Thickness: 16kÅ ±2kÅ

SUBSTRATE POTENTIAL (NOTE):

-V_{SUPPLY}

PASSIVATION:

Type: Nitride Over Silox

Nitride Thickness: 3.5kÅ ±1.0kÅ Silox Thickness: 12kÅ ±2.0kÅ

WORST CASE CURRENT DENSITY:

 $1.43 \times 10^5 \text{ A/cm}^2$

TRANSISTOR COUNT:

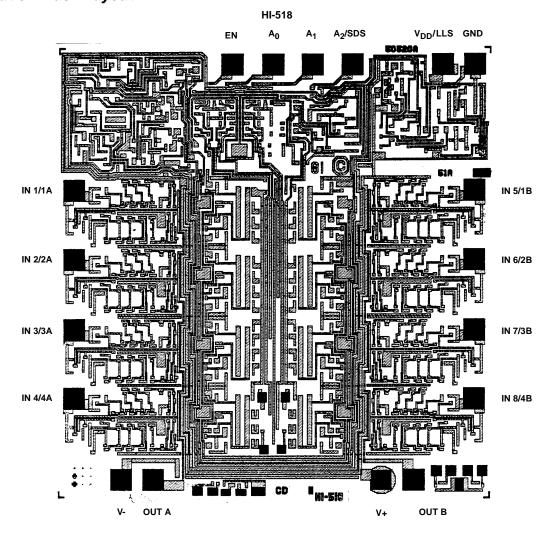
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PROCESS:

CMOS-DI

NOTE: The substrate appears resistive to the -V_{SUPPLY} terminal, therefore it may be left floating (Insulating Die Mount) or it may be mounted on a conductor at -V_{SUPPLY} potential.

Metallization Mask Layout

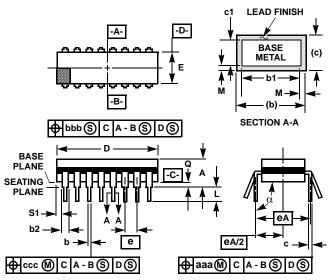


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HI-518

Ceramic Dual-In-Line Frit Seal Packages (CERDIP)



NOTES:

- Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
- The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
- Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
- Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
- 5. This dimension allows for off-center lid, meniscus, and glass overrun.
- 6. Dimension Q shall be measured from the seating plane to the base plane.
- 7. Measure dimension S1 at all four corners.
- 8. N is the maximum number of terminal positions.
- 9. Dimensioning and tolerancing per ANSI Y14.5M 1982.
- 10. Controlling dimension: INCH.

F18.3 MIL-STD-1835 GDIP1-T18 (D-6, CONFIGURATION A) 18 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE

	INC	HES	MILLIM	MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX	NOTES		
Α	-	0.200	-	5.08	-		
b	0.014	0.026	0.36	0.66	2		
b1	0.014	0.023	0.36	0.58	3		
b2	0.045	0.065	1.14	1.65	-		
b3	0.023	0.045	0.58	1.14	4		
С	0.008	0.018	0.20	0.46	2		
c1	0.008	0.015	0.20	0.38	3		
D	-	0.960	-	24.38	5		
Е	0.220	0.310	5.59	7.87	5		
е	0.100 BSC		2.54	-			
eA	0.300	BSC	7.62 BSC		-		
eA/2	0.150	BSC	3.81 BSC		-		
L	0.125	0.200	3.18	5.08	-		
Q	0.015	0.070	0.38	1.78	6		
S1	0.005	-	0.13	-	7		
α	90 ^o	105 ⁰	90°	105 ⁰	-		
aaa	-	0.015	-	0.38	-		
bbb	-	0.030	-	0.76	-		
ccc	-	0.010	-	0.25	-		
М	-	0.0015	-	0.038	2, 3		
N	1	8	1	8	8		

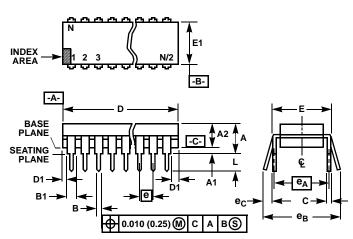
Rev. 0 4/94

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HI-518

Dual-In-Line Plastic Packages (PDIP)



NOTES:

- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and e_A are measured with the leads constrained to be perpendicular to datum -C-.
- 7. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- 10. Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3 may have a B1 dimension of 0.030 0.045 inch (0.76 1.14mm).

E18.3 (JEDEC MS-001-BC ISSUE D)
18 LEAD DUAL-IN-LINE PLASTIC PACKAGE

	INCHES		MILLIM		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
В	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8, 10
С	0.008	0.014	0.204	0.355	-
D	0.845	0.880	21.47	22.35	5
D1	0.005	-	0.13	-	5
Е	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
е	0.100	BSC	2.54	2.54 BSC	
e _A	0.300	0.300 BSC		7.62 BSC	
e _B	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	1	8	18		9

Rev. 2 11/03

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